

R-C Thermal Model Parameters

DESCRIPTION

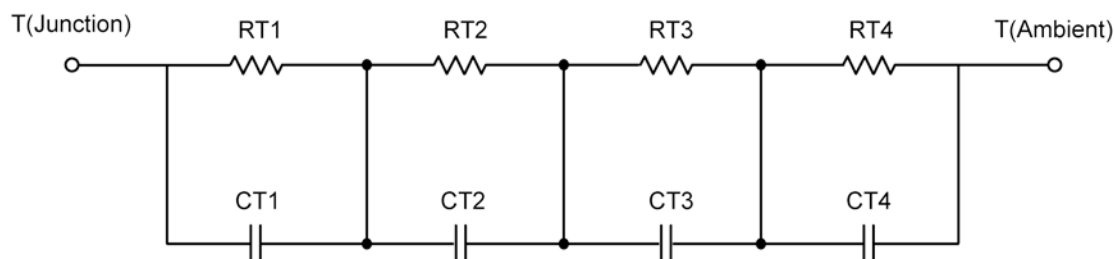
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

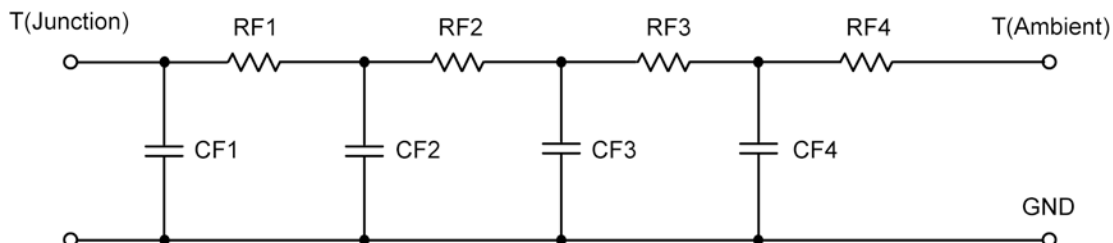
For a detailed explanation of implementing these values in P-SPIICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPIICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|--|------------|------------|------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | 27.0713 | 1.9818 | N/A |
| RT2 | 13.9534 | 1.4707 | N/A |
| RT3 | 14.8827 | 3.1117 | N/A |
| RT4 | 49.0926 | 2.9358 | N/A |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | 5.0661 m | 118.4340 u | N/A |
| CT2 | 260.9856 u | 154.0489 u | N/A |
| CT3 | 391.3129 m | 581.9782 u | N/A |
| CT4 | 2.2125 | 246.5084 u | N/A |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance (°C/W) | | | |
|---------------------------------|------------|------------|------|
| Junction to | Ambient | Case | Foot |
| RF1 | 14.3660 | 2.5823 | N/A |
| RF2 | 27.3222 | 4.5152 | N/A |
| RF3 | 18.7728 | 1.0943 | N/A |
| RF4 | 44.5390 | 1.3082 | N/A |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | 222.1962 u | 35.2139 u | N/A |
| CF2 | 4.4046 m | 53.5437 u | N/A |
| CF3 | 315.7482 m | 365.0170 u | N/A |
| CF4 | 2.0547 | 457.7854 u | N/A |

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

